

VHF variable capacitance diode Rev. 02 — 3 November 2004

Product data sheet

Product profile

1.1 General description

The BB178 is a planar technology variable capacitance diode, in a SOD523 (SC-79) ultra small plastic package. The excellent matching performance is achieved by gliding matching and a Direct Matching Assembly (DMA) procedure.

1.2 Features

- Excellent linearity
- Excellent matching to 2 % DMA
- Ultra small plastic SMD package
- $C_{d(28V)}$: 2.6 pF; $C_{d(1V)}$ to $C_{d(28V)}$ ratio: 15
- Very low series resistance.

1.3 Applications

- Electronic tuning in VHF television tuners, band B up to 460 MHz
- Voltage Controlled Oscillators (VCO).

Pinning information 2.

Table 1: **Pinning**

| Pin | Description | Simplified outline [1] | Symbol |
|-----|-------------|------------------------|--------|
| 1 | cathode | | Ш |
| 2 | anode | Top view | sym008 |

^[1] The marking bar indicates the cathode.

Ordering information 3.

Table 2: **Ordering information**

| Type number | Package | | | | | |
|-------------|---------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| BB178 | SC-79 | plastic surface mounted package; 2 leads | SOD523 | | | |



4. Marking

Table 3: Marking

| Type number | Marking code |
|-------------|--------------|
| BB178 | 8 |

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5. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|--|-----|------|------|
| V_R | reverse voltage | | - | 32 | V |
| V_{RM} | peak reverse voltage | in series with a 10 $k\Omega$ resistor | - | 35 | V |
| I _F | forward current | | - | 20 | mA |
| T _{stg} | storage temperature | | -55 | +150 | °C |
| T _j | junction temperature | | -55 | +125 | °C |

6. Characteristics

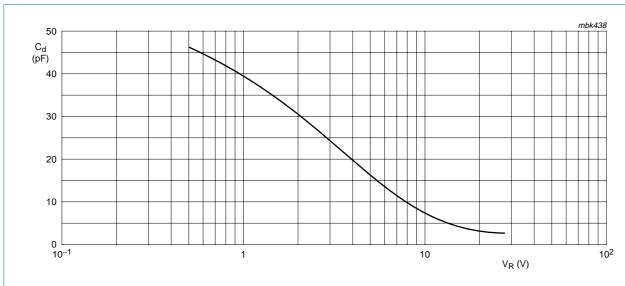
Table 5: Characteristics

 $T_i = 25$ °C unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------------------------|-------------------------|--|------------|-------|------|-------|------|
| I_R | reverse current | see Figure 2 | | | | | |
| | | $V_R = 30 \text{ V}$ | | - | - | 10 | nA |
| | | $V_R = 30 \text{ V}; T_j = 85 ^{\circ}\text{C}$ | | - | - | 200 | nA |
| r _s | diode series resistance | f = 100 MHz | <u>[1]</u> | - | 0.65 | 0.8 | Ω |
| C _d | diode capacitance | f = 1 MHz; see <u>Figure 1</u> and <u>Figure 3</u> | | | | | |
| | | $V_R = 1 V$ | | 34.65 | - | 42.35 | pF |
| | | V _R = 28 V | | 2.361 | 2.6 | 2.754 | pF |
| $\frac{C_{d(1V)}}{C_{d(2V)}}$ | capacitance ratio | f = 1 MHz | | - | 1.3 | - | |
| $\frac{C_{d(1V)}}{C_{d(28V)}}$ | capacitance ratio | f = 1 MHz | | 13.5 | 15 | - | |
| $\frac{C_{d(25V)}}{C_{d(28V)}}$ | capacitance ratio | f = 1 MHz | | - | 1.08 | - | |
| $\frac{\Delta C_d}{C_d}$ | capacitance matching | $V_R = 1 \text{ V to } 28 \text{ V; in a}$ sequence of 10 diodes (gliding) | | - | - | 2 | % |

^[1] V_R is the value at which $C_d = 30$ pF.

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 $f = 1 \text{ MHz}; T_j = 25 ^{\circ}\text{C}.$

Fig 1. Diode capacitance as a function of reverse voltage; typical values.

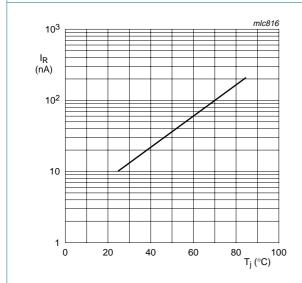
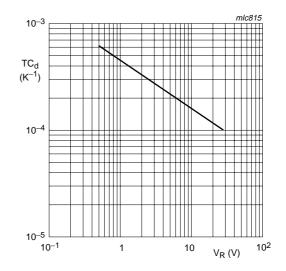


Fig 2. Reverse current as a function of junction temperature; maximum values.



 $T_j = 0$ °C to 85 °C.

Fig 3. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.

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7. Package outline

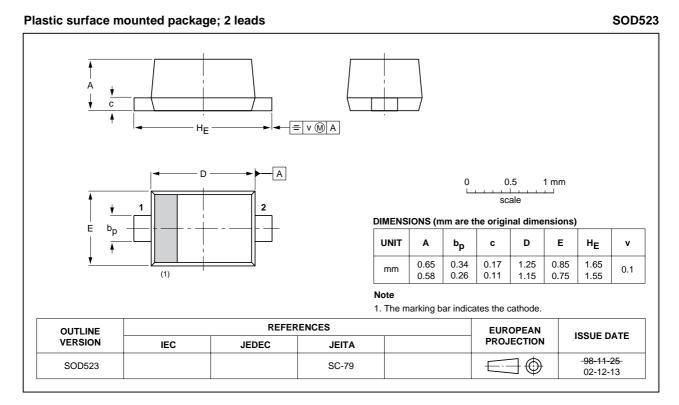


Fig 4. Package outline SOD523 (SC-79).



8. Revision history

Table 6: Revision history

| Document ID | Release date | Data sheet status | Change notice | Doc. number | Supersedes |
|----------------|--|---|-----------------------|---------------------------------|----------------------|
| BB178_2 | 20041103 | Product data sheet | - | 9397 750 13831 | BB178_1 |
| Modifications: | | t of this data sheet has b n standard of Philips Ser | • | comply with the nev | v presentation and |
| | Table 5 "C of 10 diode | haracteristics": $\Delta C_d/C_d$ coes | onditions changed f | rom sequence of 1 | 5 diodes to sequence |
| | • Table 5 "C | haracteristics": added ty | pical value of 2.6 pF | for C _{d(28V)} | |
| | Table 5 "C | haracteristics": added ty | pical value of 15 for | $C_{d(1V)}$ to $C_{d(28V)}$ rat | io. |
| BB178_1 | 19971113 | Product specification | - | 9397 750 02982 | - |

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| Level | Data sheet status [1] | Product status [2] [3] | Definition |
|-------|-----------------------|------------------------|--|
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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